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Renesas Electronics website: <http://www.renesas.com>

April 1st, 2010
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (<http://www.renesas.com>)

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MOS FIELD EFFECT TRANSISTOR μ PA2742GR

SWITCHING N-CHANNEL POWER MOSFET

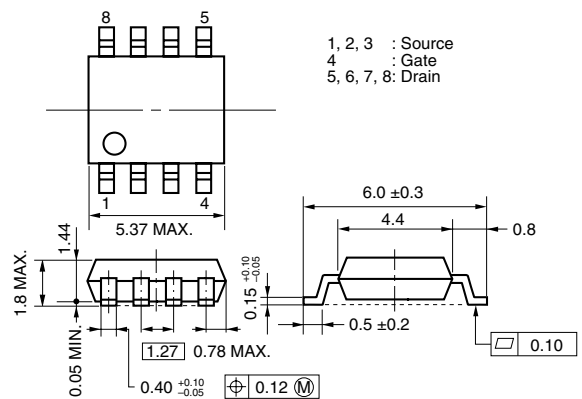
DESCRIPTION

The μ PA2742GR is N-channel MOS Field Effect Transistor designed for power management applications of a notebook computer.

FEATURES

- Low on-state resistance
 $R_{DS(on)1} = 4.8 \text{ m}\Omega \text{ MAX. (} V_{GS} = 10 \text{ V, } I_D = 9 \text{ A)}$
 $R_{DS(on)2} = 8.0 \text{ m}\Omega \text{ MAX. (} V_{GS} = 6 \text{ V, } I_D = 9 \text{ A)}$
- Low input capacitance
 $C_{iss} = 4600 \text{ pF TYP. (} V_{DS} = 10 \text{ V, } V_{GS} = 0 \text{ V)}$
- Built-in gate protection diode
- Small and surface mount package (Power SOP8)
- RoHS Compliant

PACKAGE DRAWING (Unit: mm)



ORDERING INFORMATION

PART NUMBER	LEAD PLATING	PACKING	PACKAGE
μ PA2742GR-E1-AT ^{Note}	Pure Sn	Tape 2500 p/reel	Power SOP8
μ PA2742GR-E2-AT ^{Note}			0.08 g TYP.

Note Pb-free (This product does not contain Pb in the external electrode and other parts.)

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C, All terminals are connected.)

Drain to Source Voltage (V _{GS} = 0 V)	V _{DSS}	35	V
Gate to Source Voltage (V _{DS} = 0 V)	V _{GSS}	±25	V
Drain Current (DC)	I _{D(DC)}	±17	A
Drain Current (pulse) ^{Note1}	I _{D(pulse)}	±150	A
Total Power Dissipation ^{Note2}	P _{T1}	1.1	W
Total Power Dissipation (PW = 10 sec) ^{Note2}	P _{T2}	2.5	W
Channel Temperature	T _{ch}	150	°C
Storage Temperature	T _{stg}	-55 to +150	°C
Single Avalanche Current ^{Note3}	I _{AS}	17	A
Single Avalanche Energy ^{Note3}	E _{AS}	28.9	mJ

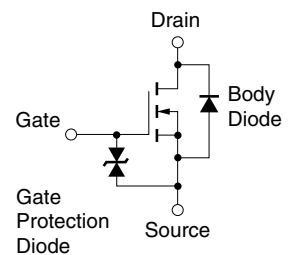
Notes 1. PW ≤ 10 μs, Duty Cycle ≤ 1%

2. Mounted on FR-4 board of 25.4 mm x 25.4 mm x 0.8 mm

3. Starting T_{ch} = 25°C, V_{DD} = 17.5 V, R_G = 25 Ω, V_{GS} = 20 → 0 V, L = 100 μH

Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

EQUIVALENT CIRCUIT



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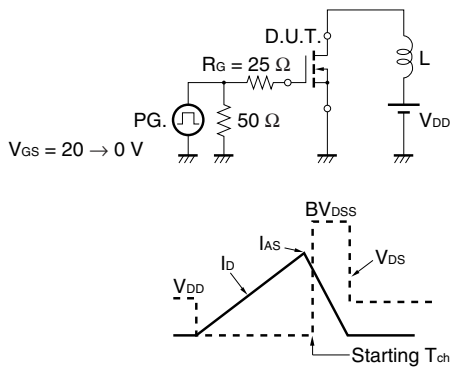
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ELECTRICAL CHARACTERISTICS (TA = 25°C, All terminals are connected.)

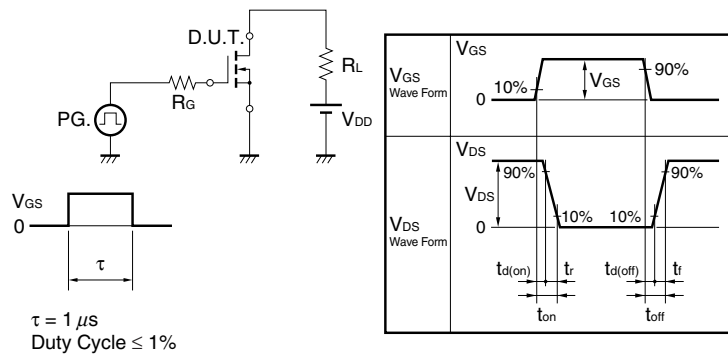
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 35\text{ V}, V_{GS} = 0\text{ V}$			1	μA
Gate Leakage Current	I_{GSS}	$V_{GS} = \pm 20\text{ V}, V_{DS} = 0\text{ V}$			±10	μA
Gate to Source Cut-off Voltage	$V_{GS(off)}$	$V_{DS} = 10\text{ V}, I_D = 1\text{ mA}$	2.0		3.0	V
Forward Transfer Admittance ^{Note}	$ y_{fs} $	$V_{DS} = 10\text{ V}, I_D = 9\text{ A}$	9			S
Drain to Source On-state Resistance ^{Note}	$R_{DS(on)1}$	$V_{GS} = 10\text{ V}, I_D = 9\text{ A}$		4	4.8	mΩ
	$R_{DS(on)2}$	$V_{GS} = 6\text{ V}, I_D = 9\text{ A}$		4.7	8.0	mΩ
Input Capacitance	C_{iss}	$V_{DS} = 10\text{ V},$		4600		pF
Output Capacitance	C_{oss}	$V_{GS} = 0\text{ V},$		830		pF
Reverse Transfer Capacitance	C_{rss}	$f = 1\text{ MHz}$		530		pF
Turn-on Delay Time	$t_{d(on)}$	$V_{DD} = 17.5\text{ V}, I_D = 9\text{ A},$		27		ns
Rise Time	t_r	$V_{GS} = 10\text{ V},$		35		ns
Turn-off Delay Time	$t_{d(off)}$	$R_G = 10\ \Omega$		99		ns
Fall Time	t_f			41		ns
Total Gate Charge	Q_G	$V_{DD} = 17.5\text{ V},$		43		nC
Gate to Source Charge	Q_{GS}	$V_{GS} = 5\text{ V},$		14		nC
Gate to Drain Charge	Q_{GD}	$I_D = 17\text{ A}$		22		nC
Body Diode Forward Voltage ^{Note}	$V_{F(S-D)}$	$I_F = 17\text{ A}, V_{GS} = 0\text{ V}$			1.2	V
Reverse Recovery Time	t_{rr}	$I_F = 17\text{ A}, V_{GS} = 0\text{ V},$		37		ns
Reverse Recovery Charge	Q_{rr}	$di/dt = 100\text{ A}/\mu\text{s}$		37		nC

Note Pulsed

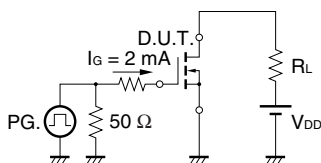
TEST CIRCUIT 1 AVALANCHE CAPABILITY



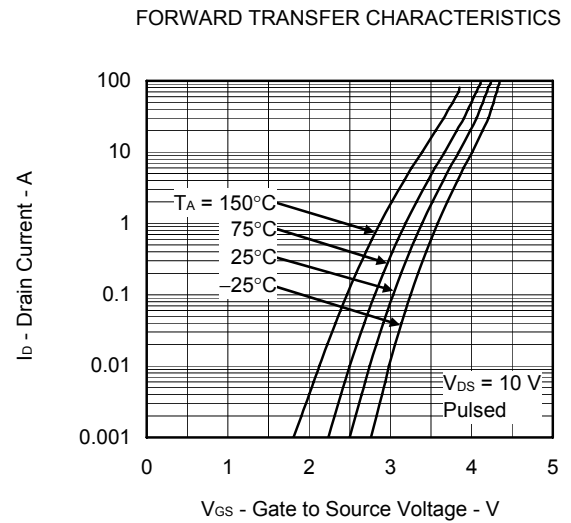
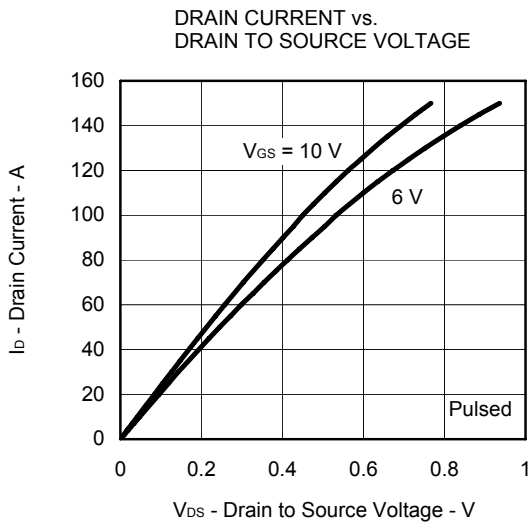
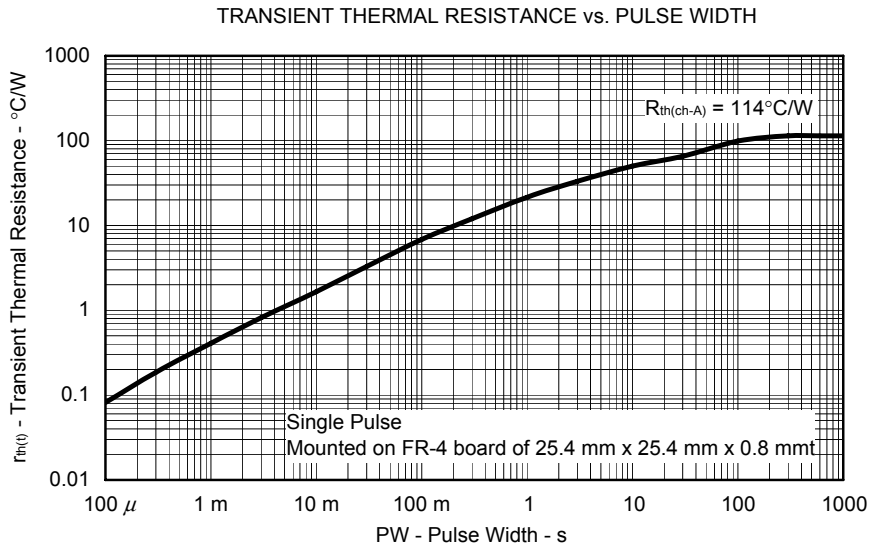
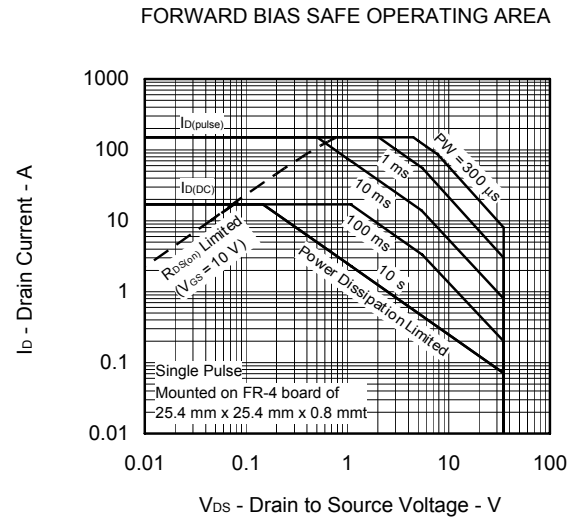
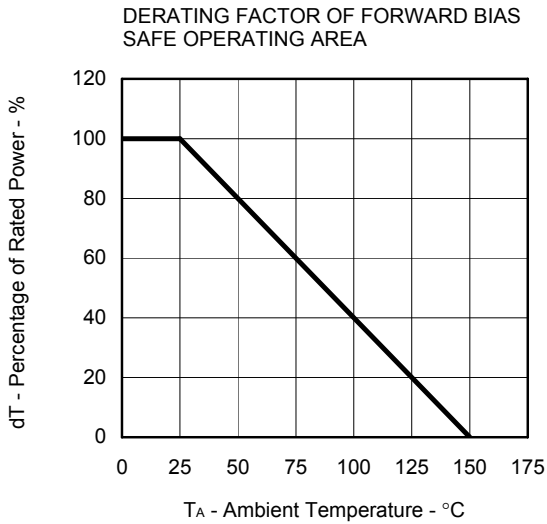
TEST CIRCUIT 2 SWITCHING TIME



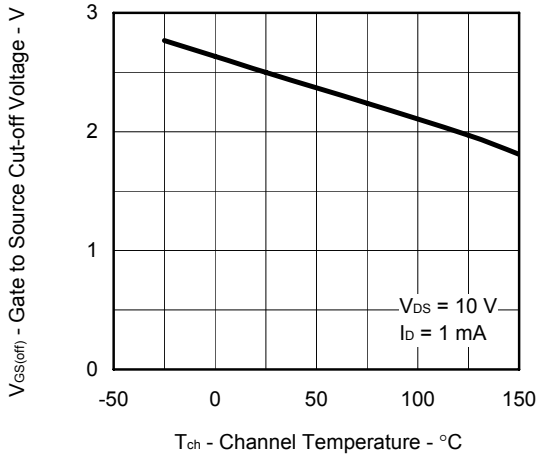
TEST CIRCUIT 3 GATE CHARGE



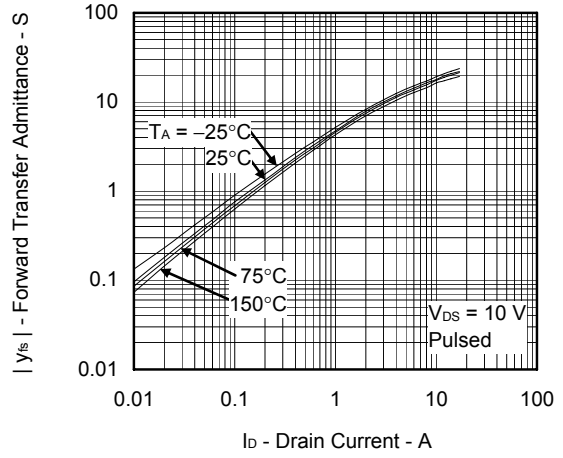
TYPICAL CHARACTERISTICS (T_A = 25°C)



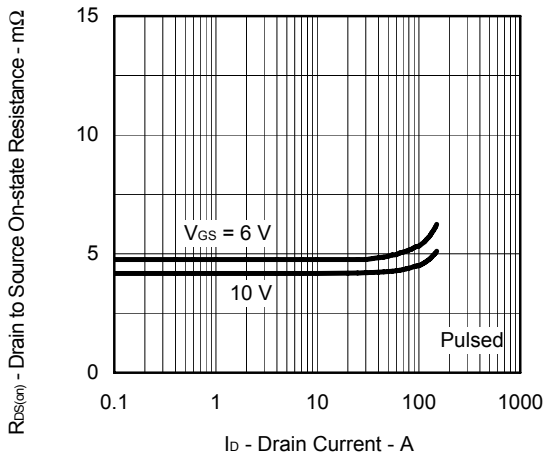
GATE TO SOURCE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE



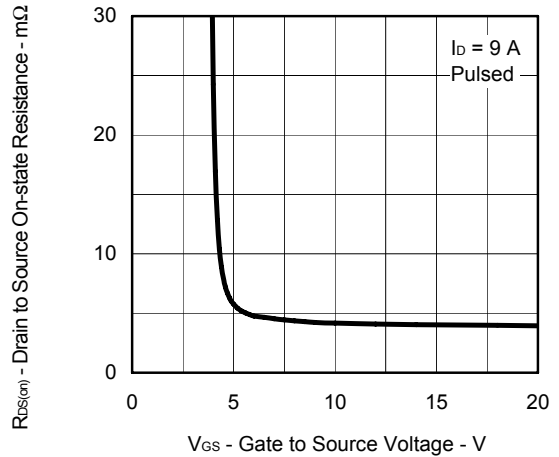
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



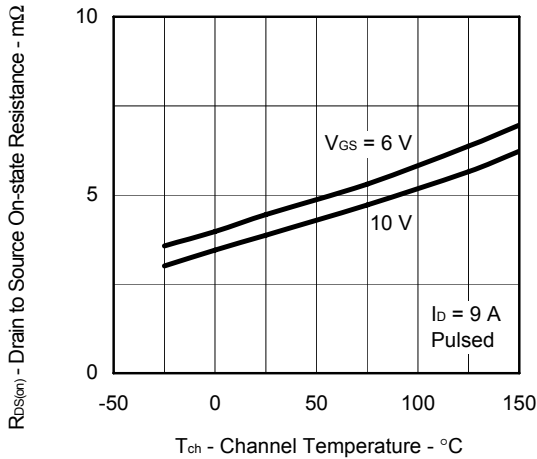
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



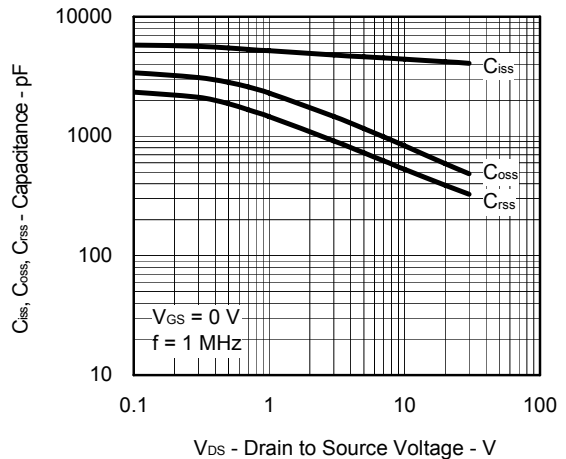
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



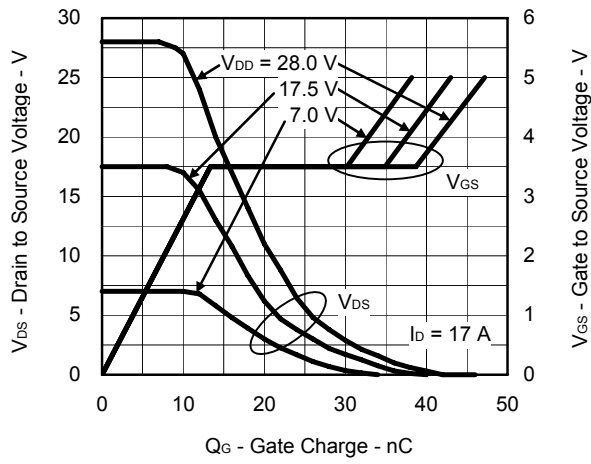
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



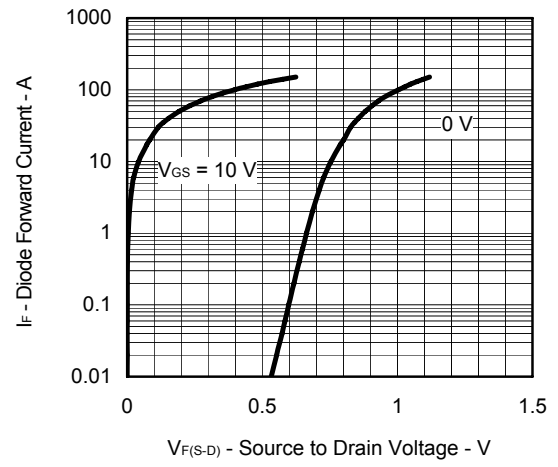
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



DYNAMIC INPUT/OUTPUT CHARACTERISTICS



SOURCE TO DRAIN DIODE FORWARD VOLTAGE



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